



P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
- 12	0.048 at V _{GS} = - 4.5 V	- 3.6		
	0.062 at V _{GS} = - 2.5 V	- 3.2		
	0.090 at V _{GS} = - 1.8 V	- 2.7		

FEATURES

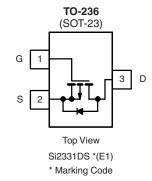
- Halogen-free Option Available
- TrenchFET® Power MOSFETS



RoHS

APPLICATIONS

- Load Switch
- PA Switch



Ordering Information: Si2331DS-T1-E3 (Lead (Pb)-free)

Si2331DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 12		V	
Gate-Source Voltage		V _{GS}	± 8			
Continuous Drain Current /T 150 °C\8	T _A = 25 °C	- I _D	- 3.6	- 3.2	_	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 2.9	- 2.6		
Pulsed Drain Current ^a		I _{DM}	- 12		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	- 0.74	- 0.59		
Daniel Birchardian	T _A = 25 °C	- P _D	0.89	0.71	W	
Power Dissipation ^a	T _A = 70 °C		0.57	0.45]	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manifestor Location to Applicated	t ≤ 5 s	- R _{thJA}	115	140	°C/W
Maximum Junction-to-Ambient ^a	Steady State		140	175	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	60	75	

Notes:

a. Surface Mounted on FR4 board.

b. t ≤ 5 s.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm.

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
			1		Limits		
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_{D} = -10 \mu\text{A}$	- 12			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 0.45		- 0.90		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvain Cuvvant	1	V _{DS} = - 12 V, V _{GS} = 0 V			- 1	<u>μ</u> Α	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 12 V, V _{GS} = 0 V, T _J = 55 °C			- 10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 6			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -3.6 \text{ A}$		0.038	0.048		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -2.5 \text{ V}, I_D = -3.2 \text{ A}$		0.049	0.062	Ω	
		$V_{GS} = -1.8 \text{ V}, I_D = -2.7 \text{ A}$		0.070	0.090		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -5 \text{ V}, I_D = -3.6 \text{ A}$		3		S	
Diode Forward Voltage	V_{SD}	I _S = - 1.6 A, V _{GS} = 0 V			- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g	V 0VV 45V		9	14	nC	
Gate-Source Charge	Q_{gs}	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}$ $I_{D} \cong -3.6 \text{ A}$		1.3			
Gate-Drain Charge	Q_{gd}	ID = - 3.0 A		2.5			
Input Capacitance	C _{iss}			780		pF	
Output Capacitance	C _{oss}	$V_{DS} = -6 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		290			
Reverse Transfer Capacitance	C _{rss}			210			
Switching ^b							
Turn-On Time	t _{d(on)}	V_{DD} = - 6 V, R_L = 6 Ω $I_D \cong$ - 1.0 A, V_{GEN} = - 4.5 V R_G = 6 Ω		20	30	- - ns	
Turn-On Time	t _r			35	55		
Turn-Off Time	t _{d(off)}			65	100		
Turn-On Time	t _f	u		50	75		

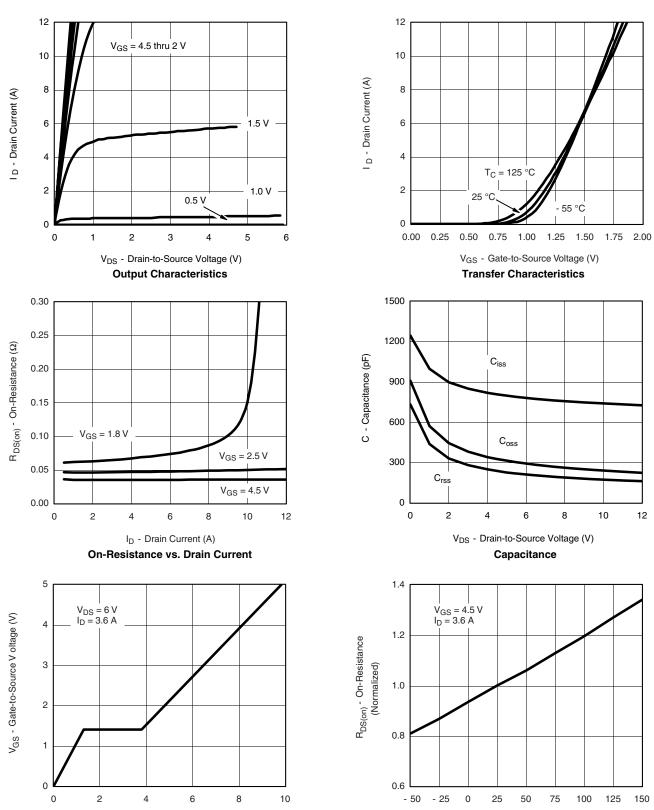
Notes:

- a. For DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.
- c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Q_g - Total Gate Charge (nC)

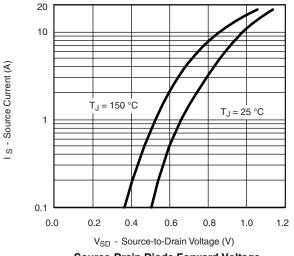
Gate Charge

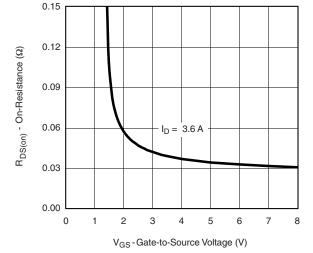
T_J - Junction Temperature (°C)

On-Resistance vs. Junction Temperature

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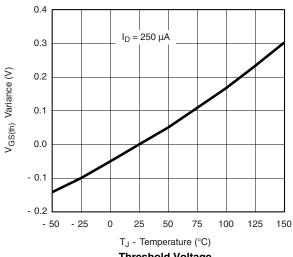
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

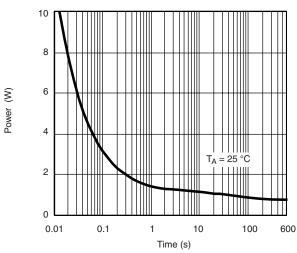




Source-Drain Diode Forward Voltage

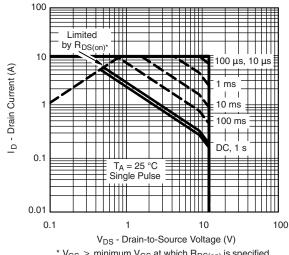
On-Resistance vs. Gate-to-Source Voltage





Threshold Voltage

Single Pulse Power

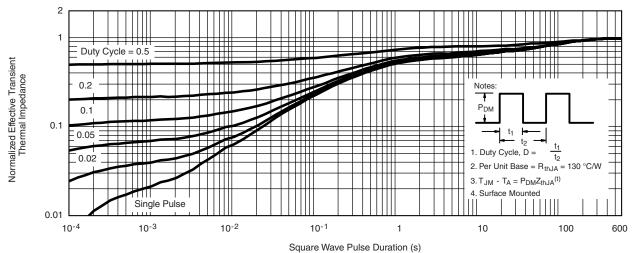


* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72152.

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